



ZVN2106G

60V N-CHANNEL ENHANCEMENT MODE VERTICAL MOSFET

Features and Benefits

- V_{(BR)DSS} > 60V
- $R_{DS(ON)} \le 2\Omega @ V_{GS} = 10V$
- Maximum Continuous Drain Current I_D = 0.71A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

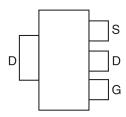
- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish @3
- Weight: 0.112 grams (Approximate)

Applications

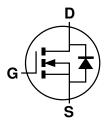
- DC-DC Converters
- · Solenoids / Relay Driver for Automotive







Pin Out - Top



Equivalent Circuit

Ordering Information (Note 4)

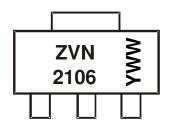
Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZVN2106GTA	ZVN2106	7	8	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

SOT223



ZVN2106 = Product Type Marking Code YWW = Date Code Marking Y or \overline{\text{Y}} = Last Digit of Year (ex: 5= 2015) WW or \overline{\text{W}} = Week Code (01~53)



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	60	V
Gate-Source Voltage	V_{GSS}	±20	V
Continuous Drain Current	I _D	0.71	Α
Pulsed Drain Current (Note 6)	I _{DM}	8	Α

Thermal Characteristics (@T_A = +25 °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 5)	T _A =+25℃	P_{D}	2	W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	∞	

Electrical Characteristics (@T_A = +25 °C, unless otherwise specified.)

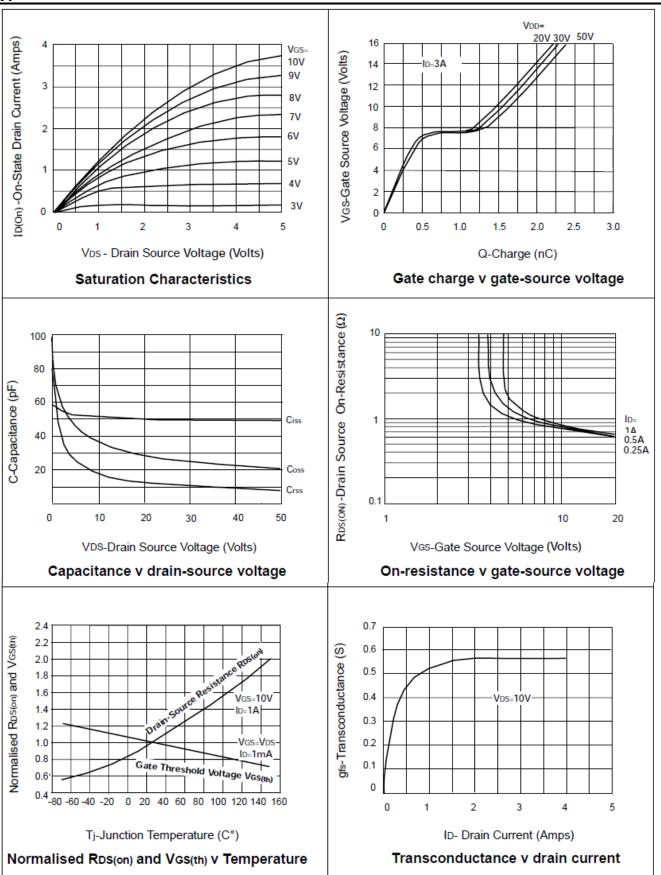
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	60	-	-	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current T _J = +25 °C	I _{DSS}	ı	-	500 100	nA μA	$V_{DS} = 60V, V_{GS} = 0V$ $V_{DS} = 48V, V_{GS} = 0V, T_{A} = +125$ °C	
Gate-Source Leakage	I _{GSS}	-	-	±20	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
On-State Drain Current	I _{D(ON)}	2	-	-	Α	$V_{GS} = 10V, V_{DS} = 18V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	$V_{GS(TH)}$	0.8		2.4	V	$V_{DS} = V_{GS}$, $I_D = 1mA$	
Static Drain-Source On-Resistance	R _{DS(ON)}	-	-	2	Ω	$V_{GS} = 10V, I_D = 1.0A$	
Forward Transconductance	g _{fs}	0.3	-	-	S	$V_{DS} = 18V, I_{D} = 1.0A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	-	-	75	рF	V _{DS} = 18V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	-	-	45	рF		
Reverse Transfer Capacitance	C _{rss}	-	-	20	рF		
Turn-On Delay Time	t _{D(ON)}	-	-	7	ns	$V_{DD} = 18V, I_D = 1A, V_{GEN} = 10V,$ $R_{GS} = 50\Omega$	
Turn-On Rise Time	t _R	-	-	8	ns		
Turn-Off Delay Time	t _{D(OFF)}	-	-	12	ns		
Turn-Off Fall Time	t _F	-	-	15	ns	1	

Notes:

- $5. \ For a \ device \ mounted \ on \ 50mm \ x \ 50mm \ x \ 1.6mm \ FR-4 \ PCB \ with \ high \ coverage \ of \ single \ sided \ 2oz \ copper, \ in \ still \ air \ condition.$
- 6. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.



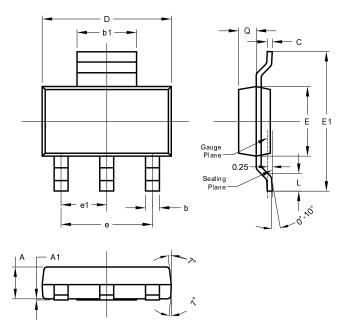
Typical Characteristics





Package Outline Dimensions

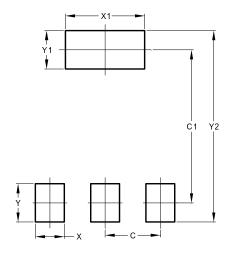
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
X	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00



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